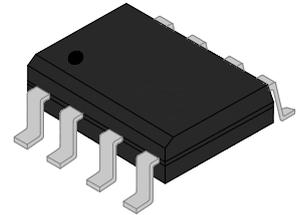




## JIP61089L Dual Programmable Thyristor Transient Voltage Suppressor Rev.3.2

### DESCRIPTION:

JIP61089L is especially designed to protect monolithic SLIC (subscriber line interfaces circuits) against transient overvoltages. Positive overloads are clipped with 2 diodes. Negative surges are suppressed by 2 thyristors, their breakdown voltage being referenced to  $-V_{BAT}$  through the gate. This component presents a very low gate triggering current ( $I_{GT}$ ) in order to reduce the current consumption on printed circuit board during the firing phase. A particular attention has been given to the internal wire bonding. The “4-point” configuration ensures reliable protection, eliminating the overvoltage introduced by the parasitic inductances of the wiring ( $Ldi/dt$ ), especially for very fast transients.



Device package type SOP-8

### FEATURES:

- ✧ Dual programmable transient suppressor.
- ✧ Wide negative firing voltage range:  $V_{GKRM} = -167V$  max .
- ✧ Low dynamic switching voltage:  $V_{FRM}$  and  $V_{GK(BD)}$ .
- ✧ Low gate triggering current:  $I_{GT} = 5mA$  max .
- ✧ Peak pulse current:  $I_{PP} = 30A$  for 10/1000 $\mu s$  surge .
- ✧ Holding current:  $I_H = 150mA$  min.
- ✧ Moisture sensitivity level: Level 3.
- ✧ UL 497B item recognized. (File No.: E480698).
- ✧ IEC61000-4-2 (ESD)  $\pm 30kV$  (air),  $\pm 30kV$  (contact).

### APPLICATION:

JIP61089L is designed to protect communication equipment such as SPC exchanger from being damaged by transient overvoltages at the second level.

### TESTING STANDARDS

| Type    | Wave Sharp             |               | $V_{PP}/I_{PP}$ |
|---------|------------------------|---------------|-----------------|
|         | ITU-T K.20/21 and K.45 | Voltage       |                 |
| Current |                        | 5/310 $\mu s$ | 40A             |

**Note 1** :The JIP61089L is intended to be used with a series combination of a 40  $\Omega$  or higher resistance and a suitable overcurrent protector. Power fault compliance requires the series overcurrent element to open-circuit or become high impedance. For equipment compliant to ITU-T recommendations K.20 or K.21 or K.45 only, the series resistor value is set by the coordination requirements. For coordination with a 400V limit GDT, a minimum series resistor value of 10 $\Omega$  is recommended.

**ABSOLUTE MAXIMUM RATINGS** ( $T_A=25^{\circ}\text{C}$ , RH=45%-75%, unless otherwise noted)

| Parameter  |  | Symbol     | Value       | Unit               |   |
|--|--|------------|-------------|--------------------|---|
| Storage temperature range                                    |  | $T_{STG}$  | -40 to +150 | $^{\circ}\text{C}$ |   |
| Operating junction temperature                               |  | $T_J$      | -40 to +150 | $^{\circ}\text{C}$ |   |
| Operating free-air temperature range                         |  | $T_A$      | -40 to +85  | $^{\circ}\text{C}$ |   |
| Non-repetitive peak on-state pulse current                   |  |            |             |                    |   |
| 10/1000 $\mu\text{s}$  | (Telcordia (Bellcore) GR-1089-CORE, Issue 2, February)             | $I_{TSP}$  | 30          | A                  |   |
| 5/310 $\mu\text{s}$  | (ITU-T K.20/21&K.45/44 open-circuit voltage 10/700 $\mu\text{s}$ ) |            | 40          |                    |   |
| 1.2/50 $\mu\text{s}$   | (Telcordia (Bellcore) GR-1089-CORE, Issue 2, February)             |            | 100         |                    |   |
| Non-repetitive peak pulse voltage(10/700 $\mu\text{s}$ )     |  | $V_{PP}$   | 2000        | V                  |   |
| Non repetitive surge peak on-state current (sinusoidal) 60Hz |  | $I_{TSM}$  | 0.5s        | 6.5                | A |
|  |  |            | 1s          | 4.6                |   |
|  |  |            | 5s          | 2.3                |   |
|  |  |            | 30s         | 1.3                |   |
|  |  |            | 900s        | 0.73               |   |
| Maximum voltage LINE/GROUND                                  |  | $V_{DRM}$  | -170        | V                  |   |
| Maximum voltage GATE/LINE                                    |  | $V_{GKRM}$ | -167        | V                  |   |

**Note 2:** 5/310 $\mu\text{s}$  means current wave, and its rise time is 5 $\mu\text{s}$ , fall time is 310 $\mu\text{s}$ .

10/700 $\mu\text{s}$  means voltage wave, and its rise time is 10 $\mu\text{s}$ , fall time is 700 $\mu\text{s}$ .

**ELECTRICAL CHARACTERISTICS** ( $T_A=25^{\circ}\text{C}$ )

| Symbol   | Parameter                     | Test conditions   | Value |      |      | Unit          |
|--|-------------------------------|---|-------|------|------|---------------|
|  |                               |   | Min.  | Typ. | Max. |               |
| Parameters related to the diode                |                               |   |       |      |      |               |
| $V_F$  | Forward voltage               | $I_F=5\text{A}$ , $t_w=200\mu\text{s}$  | -     | -    | 3    | V             |
| $V_{FRM}$                                      | Peak forward recovery voltage | 2/10 $\mu\text{s}$ , $I_F=100\text{A}$ , $R_s=50\Omega$ , $di/dt=80\text{A}/\mu\text{s}$                              | -     | -    | 10   | V             |
| Parameters related to the protection thyristor |                               |   |       |      |      |               |
| $I_{DRM}$                                      | Off-state current             | $V_{DRM}=-170\text{V}$ , $V_{GK}=0\text{V}$   | -     | -    | -5   | $\mu\text{A}$ |
| $V_{BO}$                                       | Breakover voltage             | 2/10 $\mu\text{s}$ , $I_{TM}=-100\text{A}$ , $R_s=50\Omega$ , $di/dt=-80\text{A}/\mu\text{s}$ , $V_{GG}=-100\text{V}$ | -     | -    | -112 | V             |

**ELECTRICAL CHARACTERISTICS** ( $T_A=25^{\circ}\text{C}$ , continued)

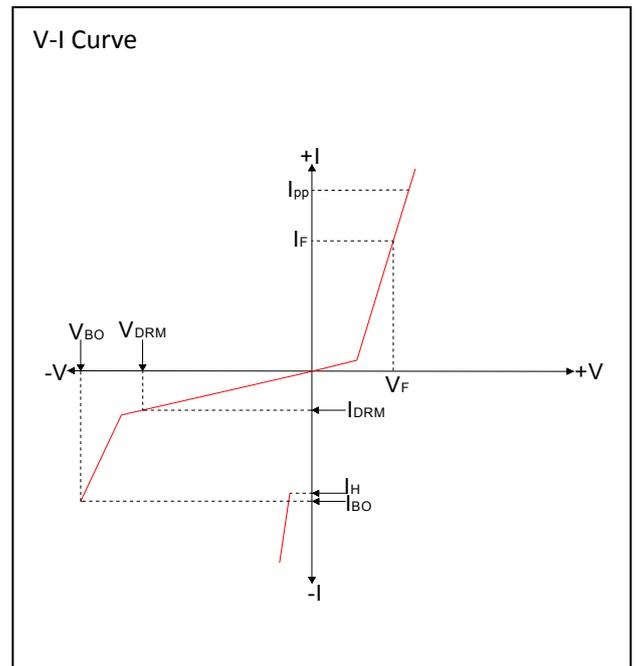
| Symbol    | Parameter                           | Test conditions   | Value |      |      | Unit          |
|-----------|-------------------------------------|---|-------|------|------|---------------|
|           |                                     |   | Min.  | Typ. | Max. |               |
| $I_H$     | Holding current                     | $I_T=-1\text{A}$ , $di/dt=1\text{A/ms}$ ,<br>$V_{GG}=-100\text{V}$        | -150  | -    | -    | mA            |
| $I_{GKS}$ | Gate reverse current                | $V_{GG}=V_{GK}=-167\text{V}$ ,<br>$V_{KA}=0$ , $T_J=25^{\circ}\text{C}$   | -     | -    | -5   | $\mu\text{A}$ |
| $I_{GT}$  | Gate trigger current                | $I_T=-3\text{A}$ , $t_P(g)\geq 20\mu\text{s}$ ,<br>$V_{GG}=-100\text{V}$  | -     | -    | 5    | mA            |
| $V_{GT}$  | Gate trigger voltage                | $I_T=-3\text{A}$ , $t_P(g)\geq 20\mu\text{s}$ ,<br>$V_{GG}=-100\text{V}$  | -     | -    | 2.5  | V             |
| $C_{AK}$  | Anode-cathode off-state capacitance | $f=1\text{MHz}$ , $V_d=1\text{V}$ , $I_G=0\text{A}$ ,<br>$V_D=-3\text{V}$ | -     | -    | 70   | pF            |

**RECOMMENDED OPERATING CONDITIONS** ( $T_A=25^{\circ}\text{C}$ )

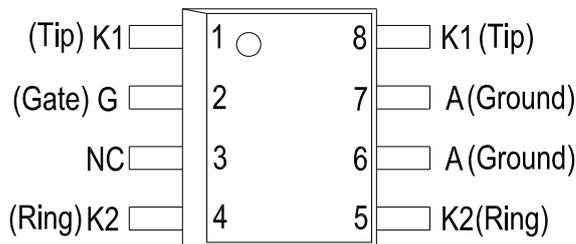
| Component |  | Value |      |      | Unit     |
|-----------|--|-------|------|------|----------|
|           |  | Min.  | Typ. | Max. |          |
| $C_G$     | Gate decoupling capacitor  | 100   | 220  | -    | nF       |
| $R_S$     | Resistor for GR-1089-CORE first-level surge survival                       | 25    | -    | -    | $\Omega$ |
|           | Resistor for GR-1089-CORE first-level and second-level surge survival      | 40    | -    | -    | $\Omega$ |
|           | Resistor for GR-1089-CORE intra-building port surge survival               | 8     | -    | -    | $\Omega$ |
|           | Resistor for K.20,K.21 and K.45 coordination with a 400V primary protector | 10    | -    | -    | $\Omega$ |

**ELECTERICAL CAHRACTERISTIC**

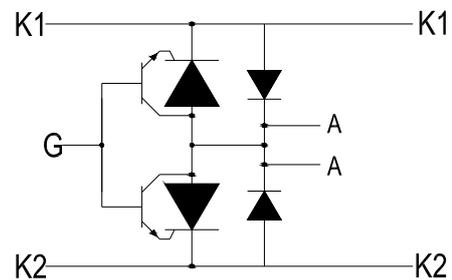
| Symbol       | Parameters                             |
|--------------|--|
| $I_{DRM}$    | Off-state current                      |
| $I_H$        | Holding current                        |
| $V_{BO}$     | Breakover voltage                      |
| $V_F$        | Forward voltage                        |
| $V_{FRM}$    | Peak forward recovery voltage          |
| $V_{GK(BD)}$ | Gate-cathode impulse breakover voltage |
| $I_{GKS}$    | Gate reverse current                   |
| $I_{GT}$     | Gate trigger current                   |
| $V_{GT}$     | Gate-cathode trigger voltage           |
| $C_{KA}$     | Cathode-anode off-state capacitance    |



**SOP PACKAGE TOP VIEW AND DEVICE SYMBOL**

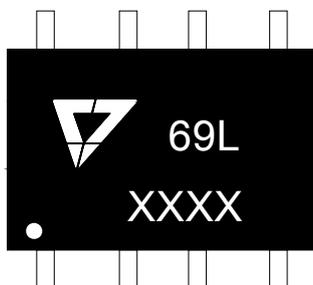


Package (Top view)



Device symbol

**MARKING**



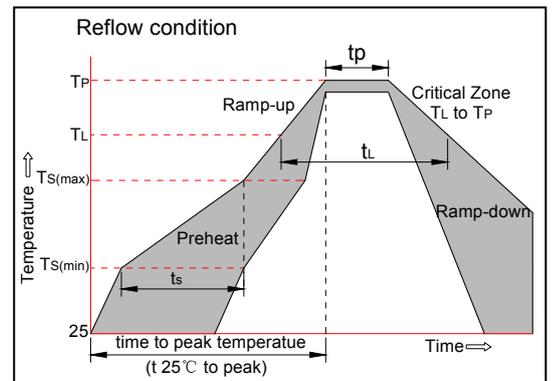
69L: Device marking code  
XXXX: Date of manufacture

**ORDERING INFORMATION**

|   |           |  |          |
|---|-----------|--|----------|
| <b>J</b>  | <b>IP</b> | <b>61089</b>                                 | <b>L</b> |
| JieJie Microelectronics CO. , Ltd<br>Integrated protection device |           | Surge ratings:10/700μs 2KV<br>Product number |          |

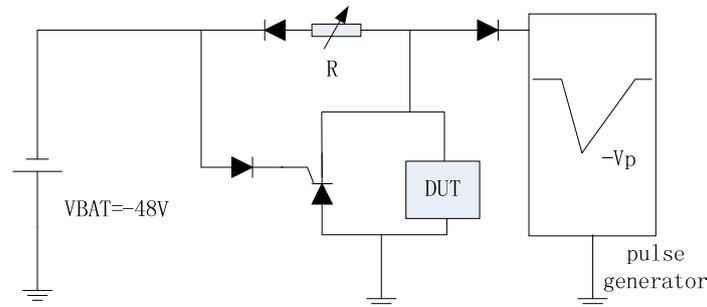
**SOLDERING PARAMETERS**

|   |                                   |   |
|---|-----------------------------------|---|
| Reflow Condition                                      |                                   | Pb-Free assembly<br>(see figure at right) |
| Pre Heat  | -Temperature Min ( $T_{s(min)}$ ) | +150°C                                    |
|   | -Temperature Max( $T_{s(max)}$ )  | +200°C                                    |
|   | -Time (Min to Max) ( $t_s$ )      | 60-180 secs.                              |
| Average ramp up rate (Liquidus Temp ( $T_L$ )to peak) |                                   | 3°C/sec. Max                              |
| $T_{s(max)}$ to $T_L$ - Ramp-up Rate                  |                                   | 3°C/sec. Max                              |
| Reflow  | -Temperature( $T_L$ )(Liquidus)   | +217°C                                    |
|   | -Temperature( $t_L$ )             | 60-150 secs.                              |
| Peak Temp ( $T_p$ )                                   |                                   | +260(+0/-5)°C                             |
| Time within 5°C of actual Peak Temp ( $t_p$ )         |                                   | 30secs.Max                                |
| Ramp-down Rate  |                                   | 6°C/sec. Max                              |
| Time 25°C to Peak Temp ( $T_p$ )                      |                                   | 8 min. Max                                |
| Do not exceed   |                                   | +260°C                                    |



**TEST METHOD AND CIRCUIT**

**Holding current test circuit (test circuit 1)**



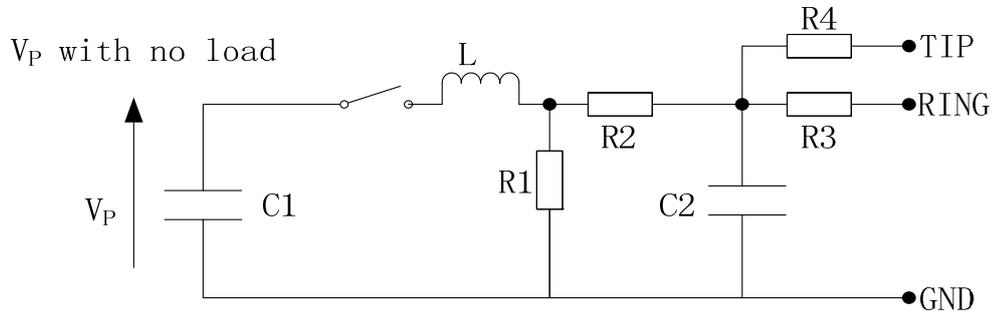
This is a conduction-cutoff test. The test circuit can ascertain the size of holding current.

Test method :

1. Short out DUT, regulating current in  $I_H$  range;

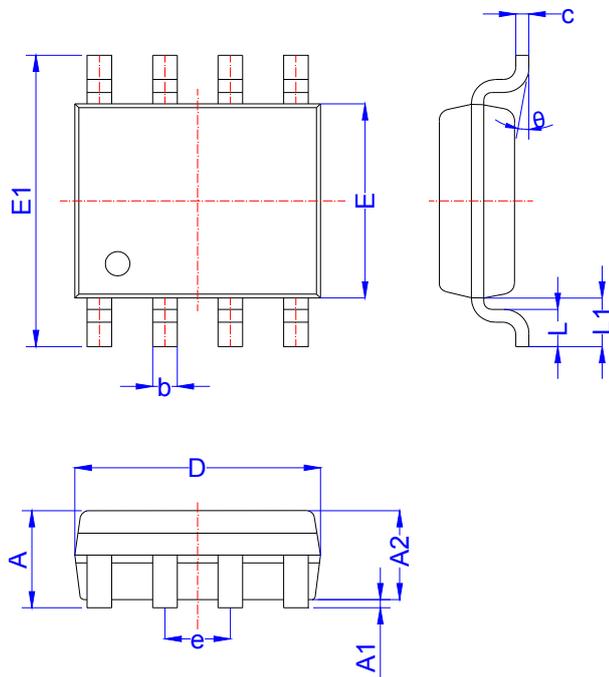
2. Triggering DUT with  $I_{PP}=10A$ , 10/1000 $\mu s$  surge current;
3. DUT needs to return to the off-state in the maximum 50ms.

**V<sub>FP</sub> and V<sub>DGL</sub> test circuit(test circuit 2)**



| Pulse( $\mu s$ )  |                   | V <sub>P</sub><br>(V) | C1<br>( $\mu F$ ) | C2<br>(nF) | L<br>( $\mu H$ ) | R1<br>( $\Omega$ ) | R2<br>( $\Omega$ ) | R3<br>( $\Omega$ ) | R4<br>( $\Omega$ ) | I <sub>PP</sub><br>(A) | R <sub>P</sub><br>( $\Omega$ ) |
|-------------------|-------------------|-----------------------|-------------------|------------|------------------|--------------------|--------------------|--------------------|--------------------|------------------------|--------------------------------|
| T <sub>rise</sub> | T <sub>fall</sub> |                       |                   |            |                  |                    |                    |                    |                    |                        |                                |
| 10                | 700               | 1500                  | 20                | 200        | 0                | 50                 | 15                 | 25                 | 25                 | 30                     | 10                             |
| 1.2               | 50                | 1500                  | 1                 | 33         | 0                | 76                 | 13                 | 25                 | 25                 | 30                     | 10                             |
| 2                 | 10                | 2500                  | 10                | 0          | 1.1              | 1.3                | 0                  | 3                  | 3                  | 38                     | 62                             |

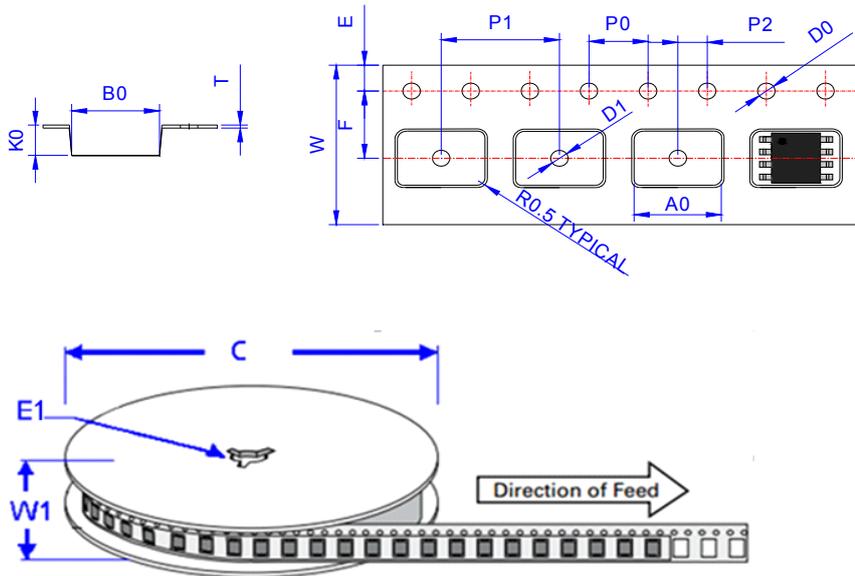
**PACKAGE MECHANICAL DATA**



SOP-8

| Ref.  | Dimensions  |      |       |        |       |       |
|-------|-------------|------|-------|--------|-------|-------|
|       | Millimeters |      |       | Inches |       |       |
|       | Min.        | Typ. | Max.  | Min.   | Typ.  | Max.  |
| A     | 1.35        |      | 1.70  | 0.053  |       | 0.067 |
| A1    | 0.04        |      | 0.18  | 0.002  |       | 0.007 |
| A2    | 1.30        |      | 1.55  | 0.051  |       | 0.061 |
| b     | 0.31        |      | 0.51  | 0.012  |       | 0.020 |
| c     | 0.17        |      | 0.25  | 0.007  |       | 0.010 |
| D     | 4.65        |      | 5.10  | 0.183  |       | 0.201 |
| E     | 3.70        |      | 4.10  | 0.146  |       | 0.161 |
| E1    | 5.80        |      | 6.20  | 0.228  |       | 0.244 |
| e     | 1.14        | 1.27 | 1.40  | 0.045  | 0.050 | 0.055 |
| L     | 0.40        |      | 0.77  | 0.016  |       | 0.030 |
| L1    | 0.825       |      | 1.225 | 0.032  |       | 0.048 |
| theta | 0°          |      | 8°    | 0°     |       | 8°    |

TAPE AND REEL SPECIFICATION-SOP-8



| Ref. | Dimensions  |               |
|------|-------------|---------------|
|      | Millimeters | Inches        |
| A0   | 6.6±0.10    | 0.260 ± 0.004 |
| B0   | 5.3±0.10    | 0.209 ± 0.004 |
| C    | 330         | 13.0          |
| D0   | 1.50±0.10   | 0.059 ± 0.004 |
| D1   | 1.50±0.10   | 0.059 ± 0.004 |
| E1   | 13.3±0.3    | 0.524± 0.012  |
| E    | 1.75±0.1    | 0.069± 0.004  |
| F    | 5.5±0.05    | 0.217 ± 0.002 |
| K0   | 2.1±0.1     | 0.083 ± 0.004 |
| P0   | 4.0±0.1     | 0.157± 0.004  |
| P1   | 8.0±0.1     | 0.315± 0.004  |
| P2   | 2.0±0.05    | 0.079 ± 0.002 |
| T    | 0.24±0.1    | 0.009 ± 0.002 |
| W    | 12.0±0.3    | 0.472 ± 0.012 |
| W1   | 15.7±2.0    | 0.618 ± 0.079 |

| PART No.  | UNIT WEIGHT (g/PCS) typ. | REEL (PCS) | PER CARTON (PCS) | DESCRIPTION       |
|-----------|--------------------------|------------|------------------|-------------------|
| JIP61089L | 0.077                    | 4,000      | 64,000           | 13 inch reel pack |

Information furnished in this document is believed to be accurate and reliable. However, Jiangsu JieJie Microelectronics Co.,Ltd assumes no responsibility for the consequences of use without consideration for such information nor use beyond it.

Information mentioned in this document is subject to change without notice, apart from that when an agreement is signed, Jiangsu JieJie complies with the agreement.

Products and information provided in this document have no infringement of patents. Jiangsu JieJie assumes no responsibility for any infringement of other rights of third parties which may result from the use of such products and information.

This document is the 3.2nd version which is made in 11-Aug.-2021. This document supersedes and replaces all information previously supplied.

 is a registered trademark of Jiangsu JieJie Microelectronics Co.,Ltd.

Copyright©2021 Jiangsu JieJie Microelectronics Co.,Ltd. Printed All rights reserved.